



Micro Commercial Components
20736 Marilla Street Chatsworth
CA 91311
Phone: (818) 701-4933
Fax: (818) 701-4939

2SB744

Features

- Capable of 10Watts of Power Dissipation.
- Collector-current 3.0A
- Collector-base Voltage 70V
- Operating and storage junction temperature range: -55°C to +150°C

Maximum Ratings

Symbol	Rating	Rating	Unit
V_{CEO}	Collector-Emmitter Voltage	45	V
V_{CBO}	Collector-Base Voltage	70	V
V_{EBO}	Emitter-Base Voltage	5.0	V
I_C	Collector Current	3.0	A
P_C	Collector power dissipation	10	W
T_J	Junction Temperature	-55 to +150	°C
T_{STG}	Storage Temperature	-55 to +150	°C

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
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OFF CHARACTERISTICS

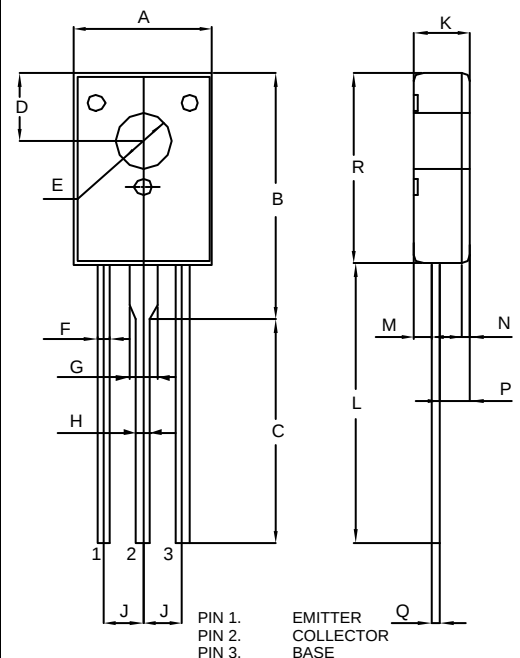
$V_{CEO(SUS)}$	Collector-Emmitter Sustaining Voltage ($I_C=1.0mA$, $I_B=0$)	45	---	Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=1.0mA$, $I_E=0$)	70	---	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=1.0mA$, $I_C=0$)	5.0	---	Vdc

ON CHARACTERISTICS

$h_{FE(1)}$	Forward Current Transfer ratio ($I_C=20mA$, $V_{CE}=5.0V$)	30	---	---
$h_{FE(2)}$	Forward Current Transfer ratio ($I_C=0.5A$, $V_{CE}=5.0V$)	60	320	---
$V_{CE(sat)}$	Collector-Emmitter Saturation Voltage ($I_C=1.5A$, $I_B=0.15A$)	---	2.0	Vdc

PNP Silicon Power Transistor

TO-126



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.30	0.33	7.70	8.30	
B		0.56		14.20	
C	0.50	0.53	12.76	13.36	
D	0.15	0.16	3.80	4.0	
E	0.12	0.13	3.10	3.30	
F	0.025	0.033	0.65	0.85	
G	0.06	0.07	1.50	1.70	
H	0.025	0.033	0.65	0.85	
J	0.08	0.10	2.08	2.48	
K	0.12	0.14	3.05	3.45	
L	0.63	0.64	15.90	16.30	
M		0.04		1.0	
N		0.02		0.5	
P	0.06	0.08	1.55	1.95	
Q	0.018	0.023	0.45	0.60	
R	0.43	0.44	10.80	11.20	